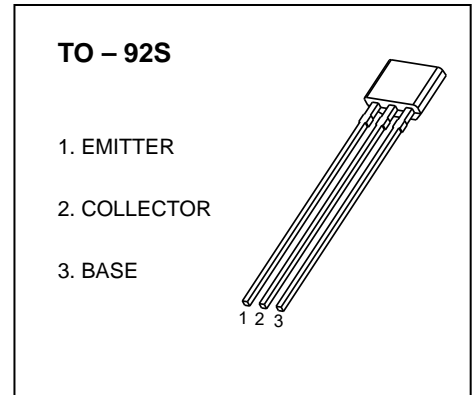


**JSCJ** JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD  
**JSCJ TO-92S Plastic-Encapsulate Transistors**

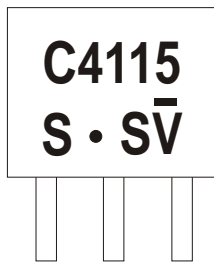
**2SC4115S** TRANSISTOR (NPN)

**FEATURES**

- Low  $V_{CE(sat)}$ .
- Excellent Current Gain Characteristics.
- Complements The 2SA1585S.

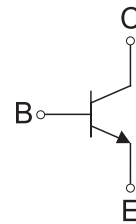


**MARKING**



C4115S=Device code  
 Solid dot = Green molding compound device,  
 if none, the normal device  
 XXX=Code

**Equivalent Circuit**



**ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
2SC4115S	TO-92S	Bulk	1000pcs/Bag
2SC4115S-TA	TO-92S	Tape	3000pcs/Box

**MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	40	V
$V_{CEO}$	Collector-Emitter Voltage	20	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_C$	Collector Current	3	A
$P_C$	Collector Power Dissipation	300	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	417	$^\circ\text{C}/\text{W}$
$T_J, T_{stg}$	Operation Junction and Storage Temperature Range	-55~+150	$^\circ\text{C}$

## ELECTRICAL CHARACTERISTICS

$T_a=25\text{ }^\circ\text{C}$  unless otherwise specified

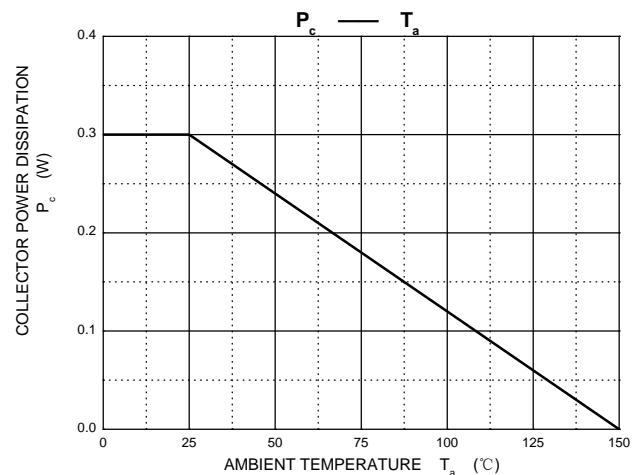
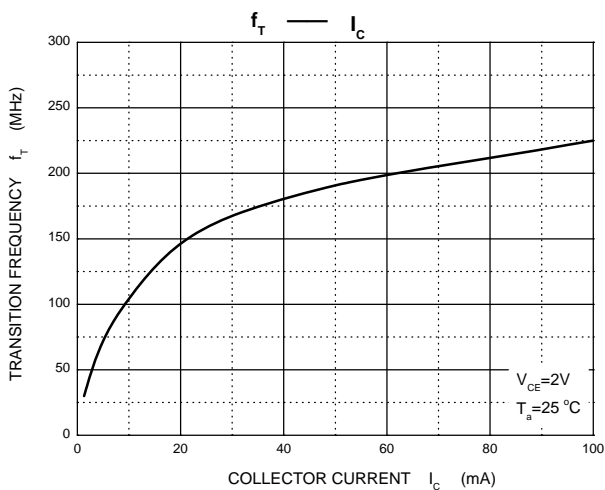
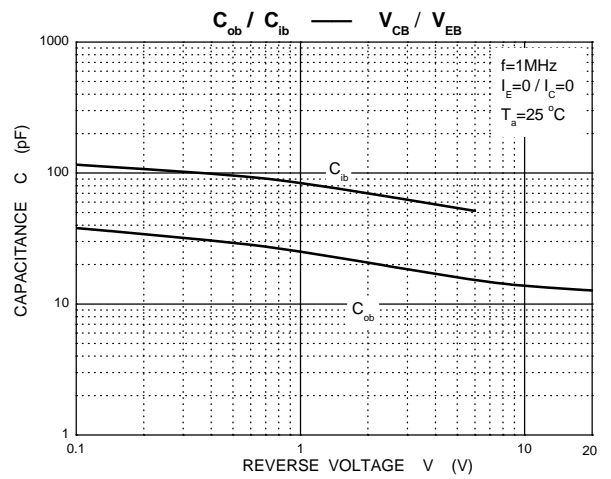
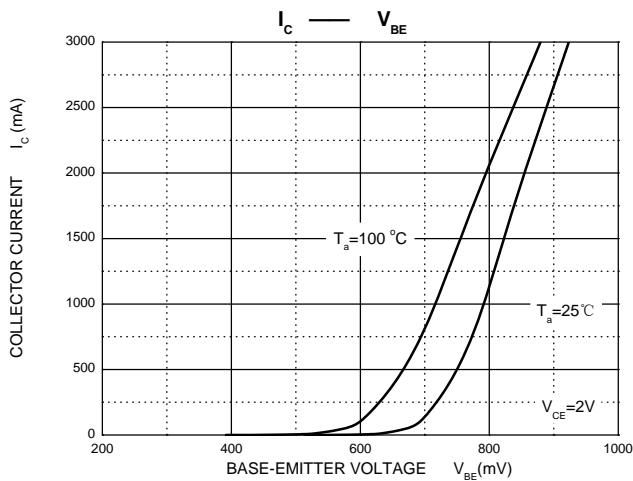
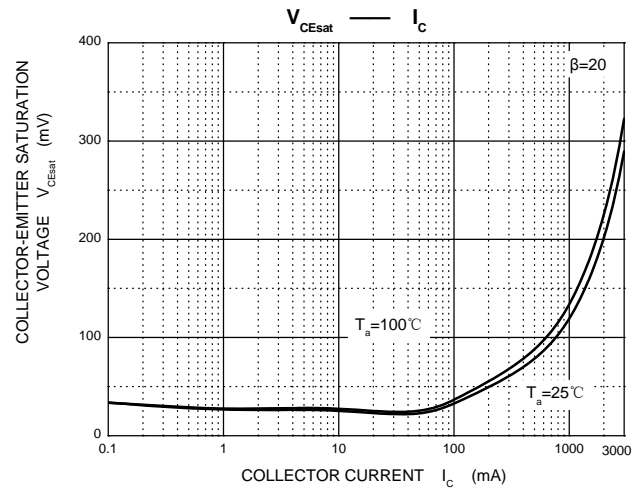
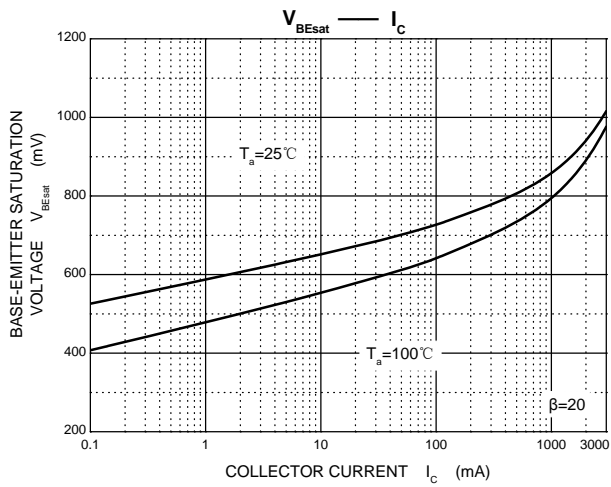
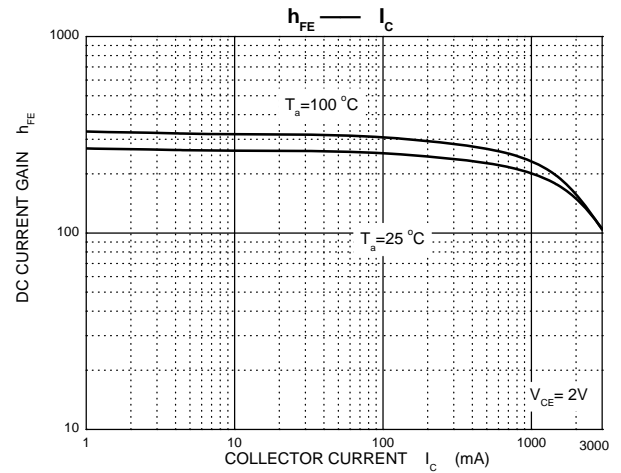
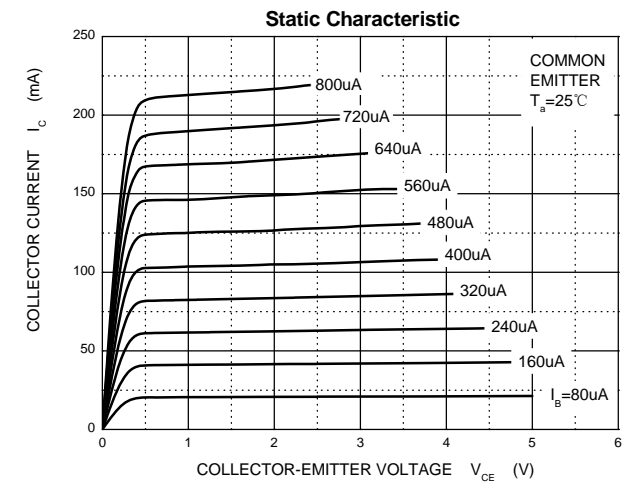
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=0.05\text{mA}, I_E=0$	40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	20			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=0.05\text{mA}, I_C=0$	6			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=30\text{V}, I_E=0$			0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=5\text{V}, I_C=0$			0.1	$\mu\text{A}$
DC current gain	$h_{FE}$	$V_{CE}=2\text{V}, I_C=100\text{mA}$	120		560	
Collector-emitter saturation voltage	$V_{CE(sat)}$ *	$I_C=2\text{A}, I_B=0.1\text{A}$			0.5	V
Collector output capacitance	$C_{ob}$	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$		25		pF
Transition frequency	$f_T$	$V_{CE}=2\text{V}, I_C=0.5\text{A}, f=100\text{MHz}$		290		MHz

\*Pulse test

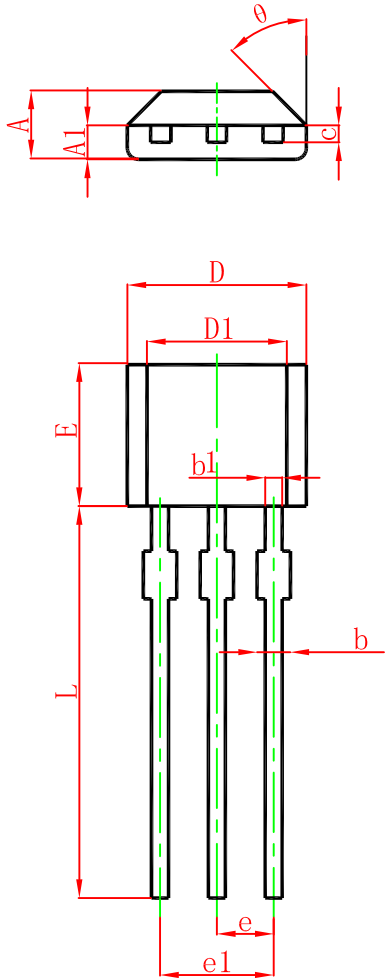
### CLASSIFICATION OF $h_{FE}$

RANK	Q	R	S
RANGE	120-270	180-390	270-560

# Typical Characteristics

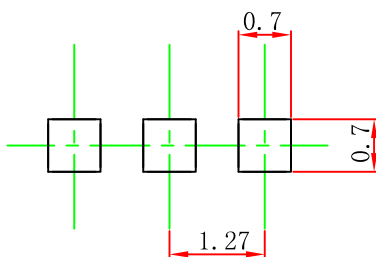


## TO-92S Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.420	1.620	0.056	0.064
A1	0.660	0.860	0.026	0.034
b	0.330	0.480	0.013	0.019
b1	0.400	0.510	0.016	0.020
c	0.330	0.510	0.013	0.020
D	3.900	4.100	0.154	0.161
D1	2.280	2.680	0.090	0.106
E	3.050	3.250	0.120	0.128
e	1.270 TYP.		0.050 TYP.	
e1	2.440	2.640	0.096	0.104
L	15.100	15.500	0.594	0.610
θ	45° TYP.		45° TYP.	

## TO-92S Suggested Pad Layout



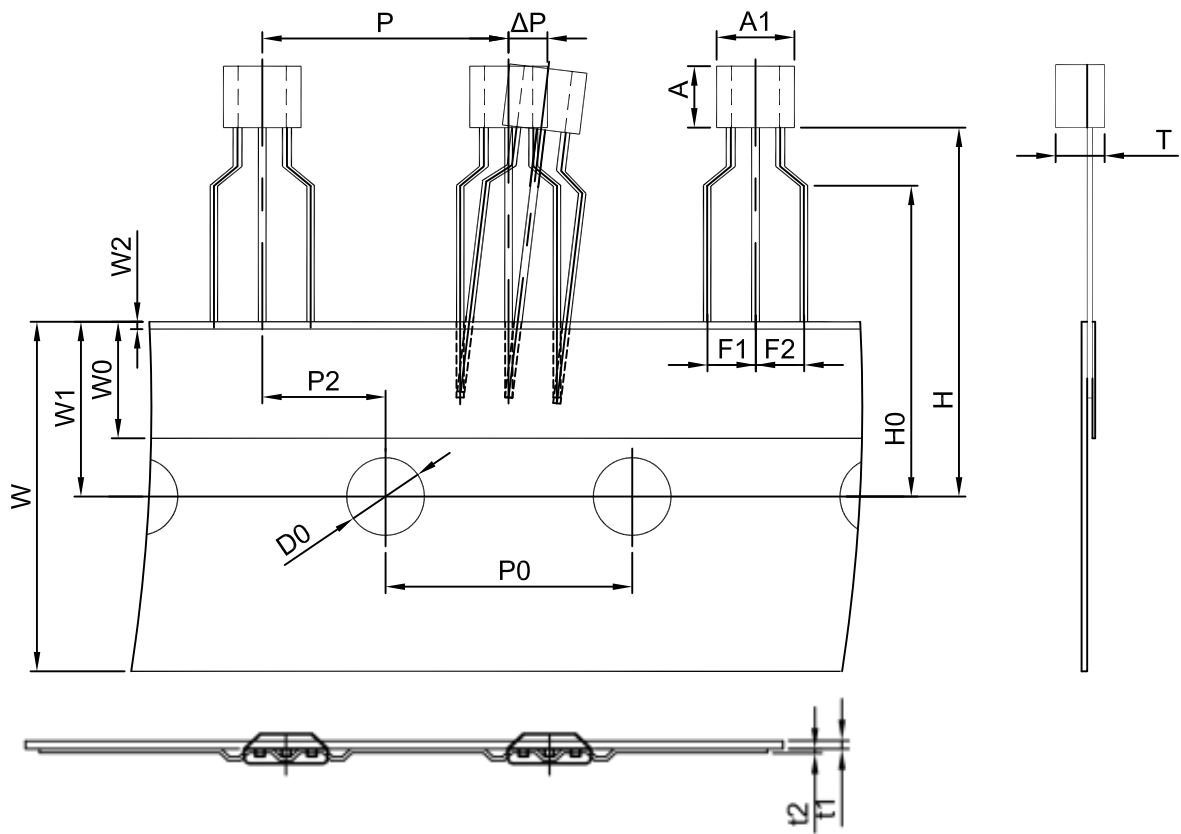
Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05$  mm.
3. The pad layout is for reference purposes only.

### NOTICE

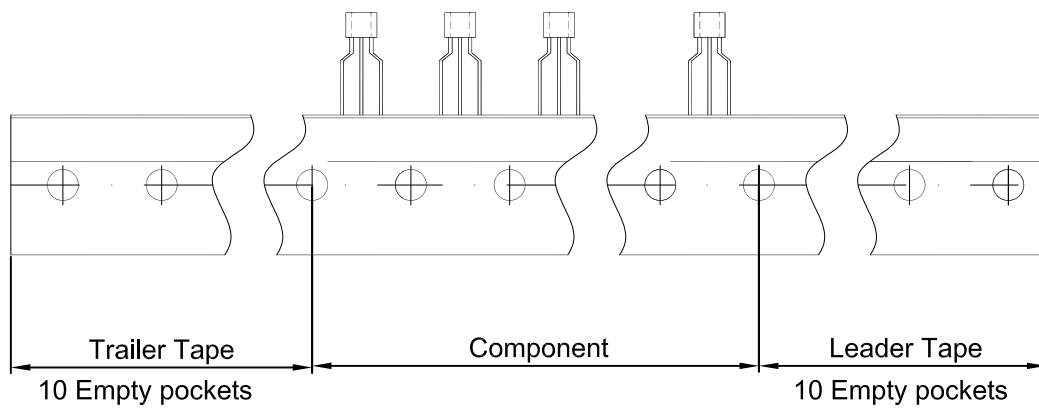
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# TO-92S PACKAGE TAPING DIMENSION



Dimensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.0	3.15	1.52	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92S	3000 pcs	333×162×43	30,000 pcs	350×340×250